Preliminary

SBRF2060CT - SBRF20200CT

Isolation 20.0 AMPS. Schottky Barrier Rectifiers **ITO-220AB**



- ♦ Plastic material used carries Underwriters Laboratory Classifications 94V-0
- ♦ Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency ∻

MICONDUCTOR

RoHS COMPLIANCE

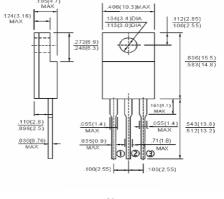
- ∻ High current capability, low forward voltage drop ∻ High surge capability
- ∻

TAIWAN

- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ♦ Guardring for overvoltage protection ♦
- High temperature soldering guaranteed: 260°C/10 seconds,0.25"(6.35mm)from case

Mechanical Data

- ♦ Cases: ITO-220AB molded plastic
- Terminals: Leads solderable per MIL-STD-750, Method 2026 Polarity: As marked $\diamond \\ \diamond$
- ∻ Mounting position: Any
- Mounting torque: 5 in. lbs. max Weight: 0.08 ounce, 2.24 grams ∻
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PIN1 O 0 PIN 3 0 PIN 2

Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

Type Number	Symbol	SBRF 2060CT	SBRF 20100CT	SBRF 20150CT	SBRF 20200CT	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	60	100	150	200	V
Maximum RMS Voltage	V _{RMS}	42	70	105	140	V
Maximum DC Blocking Voltage	V _{DC}	60	100	150	200	V
Maximum Average Forward Rectified Current at T _c =135°C Total device Per Leg	I _(AV)	20 10				А
Peak Repetitive Forward Current Per leg (Rated V_{R} , Square Wave, 20KHz) at Tc=135°C	I _{FRM}	20				А
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	150				А
Peak Repetitive Reverse Surge Current (Note 1)	I _{RRM}	0.5				А
$\begin{array}{llllllllllllllllllllllllllllllllllll$	V _F	0.80 0.70 0.95 0.85	0.85 0.75 0.95 0.85	0.95 0.85 1.05 0.95	0.99 0.87 1.23 1.10	V
Maximum Instantaneous Reverse Current @ Tc=25 °C	I _R	0.1 0.15			0.15	mA
at Rated DC Blocking Voltage @ Tc=125 °C		10			100	
Voltage Rate of Change, (Rated V _R)	dV/dt	10,000				V/uS
Typical Thermal Resistance Per Leg (Note 3)	R _{eJC}	3.5				°C /W
Typical Junction Capacitance	Cj	310				pF
RMS Isolation Voltage (MBRF Type Only) from Terminals to Heatsink with t=1.0 Second, RH \leq 30%	V _{ISO}	4500 (Note 4) 3500 (Note 5) 1500 (Note 6)				V
Operating Junction Temperature Range	TJ	-65 to +150				°C
Storage Temperature Range	Tstg	-65 to +175				°C

Notes: 1. 2.0us Pulse Width, f=1.0 KHz

2. Pulse Test: 300us Pulse Width, 1% Duty Cycle

3. Thermal Resistance from Junction to Case Per Leg, with Heatsink Size (4"x6"x0.25") Al-Plate

4. Clip mounting (on case), where lead does not overlap heatsink with 0.110" offset.

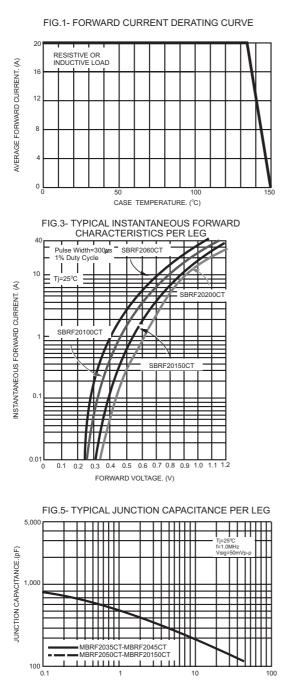
5. Clip Mounting (on case), where leads do overlap heatsink.

6. Screw Mounting with 4-40 screw, where washer diameter is \leq 4.9 mm (0.19")



RATINGS AND CHARACTERISTIC CURVES (SBRF2060CT THRU SBRF20200CT)

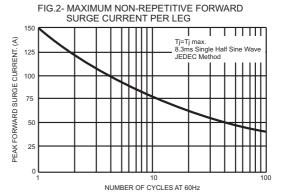
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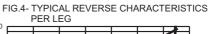


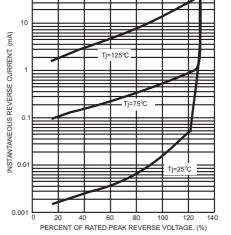
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REVERSE VOLTAGE. (V)

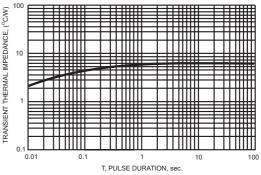
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Version: B08